



JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

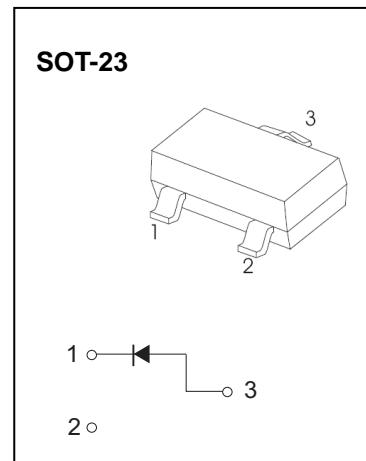
## SOT-23 Plastic-Encapsulate Diodes

### 1SS187 Switching Diode

#### FEATURES

- Low forward voltage
- Fast reverse recovery time

MARKING: D3 •



#### Maximum Ratings @Ta=25°C

Parameter	Symbol	Limit		Unit
Non-Repetitive Peak Reverse Voltage	V <sub>RM</sub>	85		V
DC Blocking Voltage	V <sub>R</sub>	80		V
Forward Continuous Current	I <sub>FM</sub>	300		mA
Average Rectified Output Current	I <sub>O</sub>	100		mA
Power Dissipation	P <sub>D</sub>	150		mW
Junction Temperature	T <sub>J</sub>	150		°C
Storage Temperature range	T <sub>STG</sub>	-55~+150		°C

#### Electrical Characteristics @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Reverse breakdown voltage	V <sub>(BR)</sub>	80			V	I <sub>R</sub> =100μA
Forward voltage	V <sub>F1</sub>		0.61		V	I <sub>F</sub> =1mA
	V <sub>F2</sub>		0.74		V	I <sub>F</sub> =10mA
	V <sub>F3</sub>		0.92	1.2	V	I <sub>F</sub> =100mA
Reverse current	I <sub>R1</sub>			0.1	uA	V <sub>R</sub> =30V
	I <sub>R2</sub>			0.5	uA	V <sub>R</sub> =80V
Capacitance between terminals	C <sub>T</sub>		2.2	4.0	pF	V <sub>R</sub> =0,f=1MHz
Reverse recovery time	t <sub>rr</sub>		1.6	4.0	ns	I <sub>F</sub> =I <sub>R</sub> =10mA,I <sub>rr</sub> =0.1×I <sub>R</sub>

# Typical Characteristics

1SS187

